Silicon Power
INDUSTRIAL

Industrial 3D NAND 2.5" SATA SSD

SSD350 SERIES

SATA III	6.0 Gbit/s
SLC Cache	3D NAND

PRODUCT FEATURES

- High-Quality 3D NAND Flash Technology
- Global Wear Leveling and Early weak block retirement
- TRIM, NCQ, DEVSLP, ATA Security Feature Set supported
- Lifetime Enhancements

  Direct-to-TLC and SLC Cache enhancement to ensure the optimized WAF

  Block/Page RAID function to ensure data recovery

  StaticDataRefresh to keep data integrity
- Reliable Industrial grade integrated Active PMU and complete protection design with OVP, OCP, surge rejection and Short protection
- External DRAM to achieve the optimal sustained read/write performance (R/S series)
- Power shielding firmware architecture to ensure power failure resilience
- Dual secure design with Advanced PFP (Power failure protection) technology to flush Data from DRAM cache to flash with dedicated polymer capacitor components while sudden power-off situations happen (R Series only)
- AES256 Encryption and TCG Opal 2.0 compliant (by request)
- SP SMART Toolbox
- SP SMART Embedded and SMART IoT service (by request)
- Ready for harsh environment design (R Series only)

  compliant with MIL-STD-810F and MIL-STD-460D for Industrial R series

PRODUCT SUMMARY

- Capacities : 64GB, 128GB, 256GB, 512GB, 1TB, 2TB
- Form Factor : 2.5" SATA Solid State Drive (70 mm x 100 mm x 7 mm)
- Compliance : SATA Revision 3.1 - 6 Gbit/s (3 Gbit/s and 1.5 Gbit/s backward compatible)
- Command Sets : Supports ATA/ATAPI-8 and ACS-2
- Performance :

	64GB	128GB	256GB	512GB	1TB	2TB
Sequential Read (MB/s Max.)	560	560	560	560	560	560
Sequential Write (MB/s Max.)	200	410	520	520	520	520
Random 4K Read (IOPS Max.)	25,000	47,000	73,000	83,000	92,000	95,000
Random 4K Write (IOPS Max.)	18,000	30,000	53,000	78,000	90,000	91,000

** Actual performance may vary based on the specific model and capacity*

- Operating Temperature Range :

  Normal : 0°C to 70°C

  Extended : -15°C to 85°C (by request)

  Wide : -40°C to 85°C (by request)
- Storage Temperature Range : -55°C to 95°C
- Operating Voltage : 5 V ± 10%
- Power Consumption :

(Unit: mA)	64GB	128GB	256GB	512GB	1TB	2TB
Read (Max.)	260	370	430	435	510	520
Write (Max.)	320	445	505	525	530	535
Stand-by (Avg.)	115	115	115	115	115	115

** Actual value may vary based on the specific model and capacity*

- Data Retention @40 °C : 10 Years @ Life Begin; 1 Year @ Life End
- Endurance in Tera Bytes Written (TBW) : *(Unit: TB)*

Workload	64GB	128GB	256GB	512GB	1TB	2TB
Sequential	187	375	750	1,500	3,000	6,000
Enterprise	29	59	118	236	471	943

TBW is estimated by formula **TBW = (Capacity x PE Cycles) x (1+OP) x (WLE) / (WAF)**

OP (Over Provision) = (Physical Capacity / Logical Capacity)-1

WAF = Write Amplification Factor

WLE = Wear Leveling Efficiency could be different depended on the workload or usage containing data size and access rate.

Sequential workload: Sequential write workload which is generated by VDBENCH script and tested by VDBENCH

Enterprise workload: Follow JESD219A enterprise workload which is generated by VDBENCH script and tested by VDBENCH.

- Mechanical (IEC-60068) :

  Vibration : 15G, 10 ~ 2001Hz

  Drop : 76cm

  Shock : 1,500G@0.6ms
- LDPC ECC engine and Block/Page RAID to ensure reliable 3K PE cycles
- Mean Time Between Failure : > 2,000,000 hours
- Data Reliability: Non-recover Read (UBER) ≤10^{-16}
- Serious quality control and assurance

  100% NAND Flash screening

  High endurance product design with 3D NAND and pSLC product offerings

  Implement high/low temperature dynamic burn-in in each lot production to monitor production quality to meet design specification

  Reliability criteria compliant with international standards IEC-60068/61000